


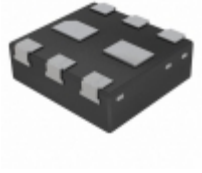
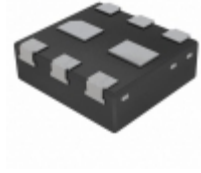

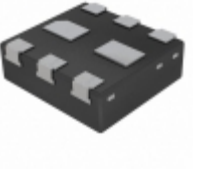
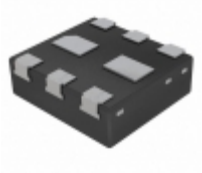
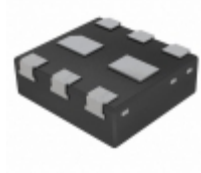
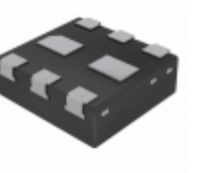
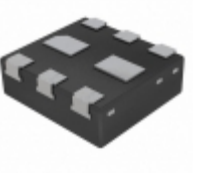
	<h2 style="color: #E67E22;">PMDXB950UPE</h2>	
	Hersteller-Teilenummer:	PMDXB950UPE
	Hersteller / Marke:	Nexperia
	Teil der Beschreibung:	MOSFET 2P-CH 20V 0.5A 6DFN
Datenblätter:	 PMDXB950UPE.pdf	
RoHs Status:	Bleifrei / RoHS-konform	
Lagerzustand:	New original, 4655 pcs Stock Available.	
Liefern von:	Hong Kong	
Versandweg:	DHL/Fedex/TNT/UPS/EMS	
<p>Image may be representation. See specs for product details.</p>		

Spezifikationen

Teilenummer	PMDXB950UPE
Hersteller	Nexperia
Beschreibung	MOSFET 2P-CH 20V 0.5A 6DFN
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	4655 pcs Stock
Serie	TrenchFET®
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Leistung - max	265mW
Verpackung / Gehäuse	6-XDFDN Exposed Pad
Supplier Device-Gehäuse	6-DFN (1.1x1)
Typ FET	2 P-Channel (Dual)
FET-Merkmal	Logic Level Gate
Drain-Source-Spannung (Vdss)	20V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	500mA
Rds On (Max) @ Id, Vgs	1.4 Ohm @ 500mA, 4.5V
VGS (th) (Max) @ Id	950mV @ 250µA
Gate Charge (Qg) (Max) @ Vgs	2.1nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	43pF @ 10V
Verpackung	Tape & Reel (TR)



















































PMDXB950UPE ist neu im Original, Suche PMDXB950UPE Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie PMDXB950UPE Nexperia mit Garantie und Vertrauen.
Anfrage PMDXB950UPE: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>PMDXB600UNEZ Nichicon MOSFET 2N-CH 20V 0.6A 6DFN</p>	 <p>PMDXB950UPE Nichicon MOSFET 2P-CH 20V 0.5A 6DFN</p>	 <p>PMDT670UPE,115 Nexperia MOSFET 2P-CH 20V 0.55A SOT666</p>	 <p>PMDXB1200UPEZ Nexperia MOSFET 2P-CH 30V 0.41A 6DFN</p>
 <p>PMDXB550UNEZ Nexperia MOSFET 2N-CH 30V 0.59A 6DFN</p>	 <p>PMDXB600UNEZ Nexperia MOSFET 2N-CH 20V 0.6A 6DFN</p>	 <p>PMDXB600UNE Nexperia PMDXB600UNE Nexperia USA Inc.</p>	 <p>PMDXB950UPEZ Nexperia MOSFET 2P-CH 20V 0.5A 6DFN</p>

heiße Teile

Mehr

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 FDPF44N25TRDTU	 LH28F160BVE	 D LT1021DIN-10	 MAX9018AEKA	 N0180SH160
 P0720SBLRP	 PMD4001K	 PMD4003K	 PMD4118OWSR	 PMD5001K
 D PMD5002K	 PMD5003K	 PMD505S05HS	 PMD605S3.3HS-R1	 PMD9001D
 PMD9002D	 PMD9003D	 PMD9010D	 PMD9050D	 PMDB75T6
 PMDPB28UN	 PMDPB42UN	 D PMDPB55XP	 PMDPB56XN	 PMDPB58UPE
 PMDPB65UP	 D PMDPB70EN	 PMDPB70XP	 PMDPB80XP	 PMDT290UCE
 PMDT290UNE	 PMDT670UPE	 PMDXB600UNE	 PMDXB950UPE	 RD12FM-T1
 REF102CP	 S-24CS08AFJ-TB	 SG400EX22	 D SKN50/08	 SM3024NSU
 SM3119NAUC-TRG	 SM6S26A-E3/2D	 SMT-MJ110BU	 TSA5526AM/C2	 TSTA7500

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HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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